Renesas RD74LVC1G17

Schmitt-trigger Buffer

REJ03D0722-0100 Rev.1.00 Feb 23, 2006

Description

The RD74LVC1G17 has a Schmitt-trigger buffer in a 5-pin package. Low voltage and high-speed operation is suitable for the battery powered products (e.g., notebook computers), and the low power consumption extends the battery life.

Features

- The basic gate function is lined up as Renesas uni logic series. •
- Supply voltage range : 1.65 to 5.5 V ٠
- Operating temperature range: -40 to $+85^{\circ}$ C
- V_{IH} (Max.) = 5.5 V (@V_{CC} = 0 V to 5.5 V) • All inputs:
- All outputs: V_0 (Max.) = 5.5 V (@V_{CC} = 0 V)
- Output current: $\pm 4 \text{ mA} (@V_{CC} = 1.65 \text{ V})$
 - $\pm 8 \text{ mA} (@V_{CC} = 2.3 \text{ V})$ $\pm 24 \text{ mA} (@V_{CC} = 3.0 \text{ V})$ $\pm 32 \text{ mA} (@V_{CC} = 4.5 \text{ V})$

Ordering Information •

		e		
• Supply voltage range :	1.65 to 5.5 V			
Operating temperature	range: -40 to $+85^{\circ}C$			
• All inputs: V _{IH} (Ma	$(x.) = 5.5 V (@V_{CC} = 0)$) V to 5.5 V)		
• All outputs: V ₀ (Max	$x.) = 5.5 V (@V_{CC} = 0)$	V)		
• Output current:	$\pm 4 \text{ mA} (@V_{CC} = 1.65)$	5 V)		
	$\pm 8 \text{ mA} (@V_{CC} = 2.3)$	V)		
	$\pm 24 \text{ mA} (@V_{CC} = 3.0)$) V)	G	
	$\pm 32 \text{ mA} (@V_{CC} = 4.5)$	5 V)		
Ordering Information		0' 1	0	
Part Name	Package Type	Package Code	Package	Taping Abbreviation
		(Previous Code)	Abbreviation	(Quantity)
RD74LVC1G17WPE	WCSP-5 pin	SXBG0005LB-A	WP	E (3,000 pcs/reel)
		(TBS-5CV)		

Article Indication

Marking	
	Year code
	Month code
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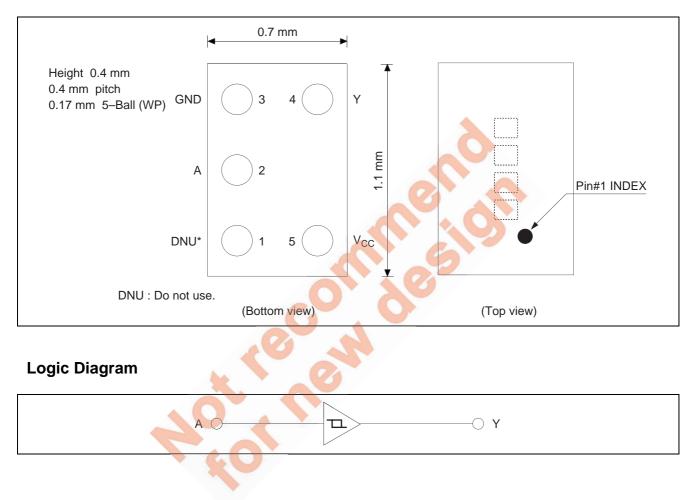
Function Table

Input A	Output Y
Н	Н
L	L

H: High level

L: Low level

Pin Arrangement





Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Test Conditions
Supply voltage range	Vcc	-0.5 to 6.5	V	
Input voltage range ^{*1}	VI	-0.5 to 6.5	V	
Output voltage range *1, 2	Vo	–0.5 to V _{CC} +0.5	V	Output : H or L
		-0.5 to 6.5		V _{CC} : OFF
Input clamp current	I _{IK}	-50	mA	V ₁ < 0
Output clamp current	I _{OK}	-50	mA	V ₀ < 0
Continuous output current	Ιo	±50	mA	$V_0 = 0$ to V_{CC}
Continuous current through	I _{CC} or I _{GND}	±100	mA	
V _{CC} or GND				
Package Thermal impedance	$ heta_{ja}$	200	°C/W	WP
Storage temperature	Tstg	-65 to 150	°C	

Notes: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore no two of which may be realized at the same time.

- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 5.5 V maximum.

Recommended Operating Conditions

2. This value is limited to	5.5 V maximur	n.			
Recommended Operation	ng Conditio	ons	~		
Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	V _{cc}	1.65	5.5	V	
Input voltage range	VI	0	5.5	V	
Output voltage range	Vo	0	Vcc	V	
Output current	IOL		4	mA	V _{CC} = 1.65 V
	0	-	8		V _{CC} = 2.3 V
			16		$V_{CC} = 3.0 V$
		-	24		
			32		$V_{CC} = 4.5 V$
	Іон	_	-4		V _{CC} = 1.65 V
		_	-8		V _{CC} = 2.3 V
		_	-16		$V_{CC} = 3.0 V$
• · · · ·		_	-24		
			-32		V _{CC} = 4.5 V
Operating free-air temperature	Ta	-40	85	°C	

Note: Unused or floating inputs must be held high or low.

Electrical Characteristics

Ta = -40 to $85^{\circ}C$

ltem	Symbol	V _{cc} (V)	Min	Тур	Max	Unit	Test condition
Threshold voltage	V _T ⁺	1.8	0.8	_	1.4	V	
		2.5	1.2	_	1.7		
		3.3	1.6	—	2.3		
		5.0	2.3	_	3.0		
	V _T ⁻	1.8	0.4	_	0.7		
		2.5	0.6	—	1.0		
		3.3	0.9	—	1.4		
		5.0	1.5	—	2.0		
	ΔV_T	1.8	0.4	—	0.7		
		2.5	0.4	—	0.8		
		3.3	0.4	—	0.9		
		5.0	0.4	—	1.0		
Output voltage	V _{OH}	1.65 to 5.5	V _{CC} -0.1	—	-	V	I _{OH} = −100 μA
		1.65	1.2	—			I _{ОН} = —4 mA
		2.3	1.9	—		-	I _{ОН} = –8 mA
		3.0	2.4	—	• <u>}</u> _6		I _{он} = –16 mA
			2.3	-	-		I _{ОН} = –24 mA
		4.5	3.8		Y	5	I _{OH} = –32 mA
	Vol	1.65 to 5.5	—		0.1		I _{OL} = 100 μA
		1.65		—	0.45		I _{OL} = 4 mA
		2.3		-	0.3		I _{OL} = 8 mA
		3.0			0.4		I _{OL} = 16 mA
			5	-	0.55		I _{OL} = 24 mA
		4.5			0.55		I _{OL} = 32 mA
Input current	l _{in}	0 to 5.5		_	±5	μA	$V_{IN} = 5.5 V \text{ or GND}$
Quiescent	Icc	5.5		—	10	μΑ	$V_{IN} = V_{CC}$ or GND,
supply current							I _O = 0
	Δlcc	3 to 5.5	-	—	500		One input at V _{CC} –0.6 V,
							Other input at V _{CC} or GND
Output leakage current	IOFF	0	—	—	±10	μA	V_{IN} or $V_O = 0$ to 5.5 V
Input capacitance	CIN	3.3	—	3.5	_	pF	$V_{IN} = V_{CC} \text{ or } GND$
			1		1		

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

Switching Characteristics

 $V_{CC} = 1.8 \pm 0.15 \text{ V}$

						•=	1.0 ± 0.15				
		Ta = -40 to 85°C		Ta = -40 to 85°C		Ta = -40 to 85°C				FROM	то
Item	Symbol	Min	Max	Unit	Test Conditions	(Input)	(Output)				
Propagation delay time	t _{PLH}	2.8	9.9	ns	C_L = 15 pF, R_L = 1 M Ω	A	Y				
	t _{PHL}	3.8	11.0		$C_L = 30 \text{ pF}, R_L = 1.0 \text{ k}\Omega$]					

 $V_{CC}=2.5\pm0.2~V$

		Ta = -40 to 85°C				FROM	то
Item	Symbol	Min	Max	Unit	Test Conditions	(Input)	(Output)
Propagation delay time	t _{PLH}	1.6	5.5	ns	$C_L = 15 \text{ pF}, R_L = 1 \text{ M}\Omega$	А	Y
	t _{PHL}	2.0	6.5		C_L = 30 pF, R_L = 500 Ω		

 $V_{CC}=3.3\pm0.3~V$

	Ta = -40 to 85°C				FROM	то
Symbol	Min	Мах	Unit	Test Conditions	(Input)	(Output)
t _{PLH}	1.5	4.6	ns	$C_L = 15 \text{ pF}, R_L = 1 \text{ M}\Omega$	А	Y
t _{PHL}	1.8	5.5		$C_{L} = 50 \text{ pF}, R_{L} = 500 \Omega$		
	t _{PLH}	Symbol Min t _{PLH} 1.5	Symbol Min Max t _{PLH} 1.5 4.6	SymbolMinMaxUnittpLH1.54.6ns	SymbolMinMaxUnitTest Conditions t_{PLH} 1.54.6ns $C_L = 15 \text{ pF}, R_L = 1 \text{ M}\Omega$	SymbolMinMaxUnitTest Conditions(Input) t_{PLH} 1.54.6ns $C_L = 15 \text{ pF}, R_L = 1 \text{ M}\Omega$ A

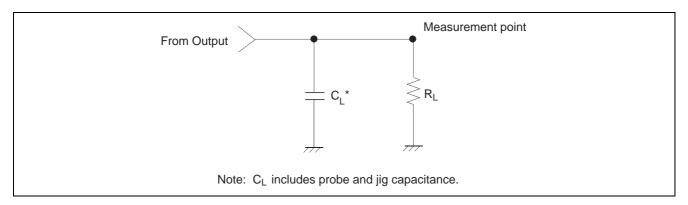
$V_{CC} = 5.0 \pm 0.5 \text{ V}$

		Ta = -40 to 85°C				FROM	то
Item	Symbol	Min	Max	Unit	Test Conditions	(Input)	(Output)
Propagation delay time	t _{PLH}	0.9	4.4	ns	$C_L = 15 \text{ pF}, R_L = 1 \text{ M}\Omega$	А	Y
	t _{PHL}	1.2	5.0		$C_L = 50 \text{ pF}, R_L = 500 \Omega$		

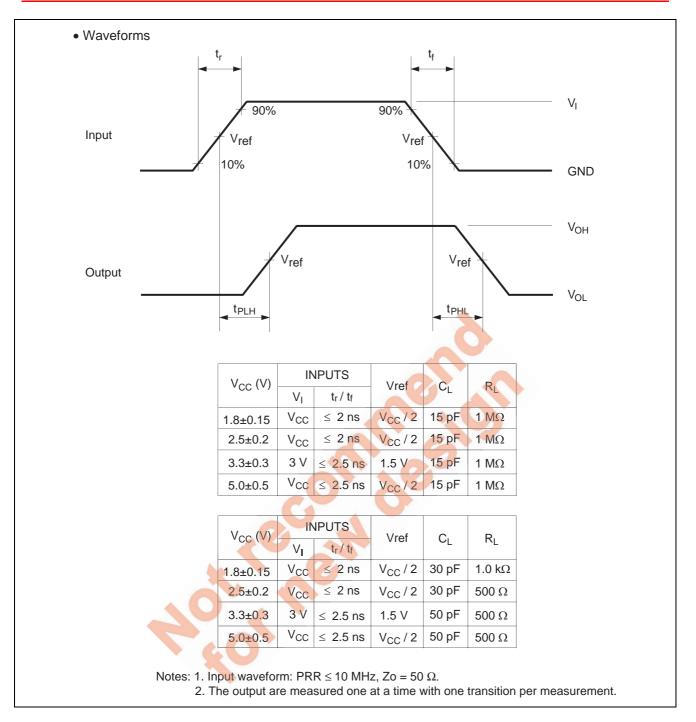
Operating Characteristics

		9	5	Ta = 25°C			
Item	Symbol	Vcc (V)	Min	Тур	Max	Unit	Test Conditions
Power dissipation capacitance	CPD	1.8	_	20	_	pF	f = 10 MHz
		2.5	_	21	_		
	4.0	3.3	—	22	_		
	X	5.0	—	26	—		

Test Circuit

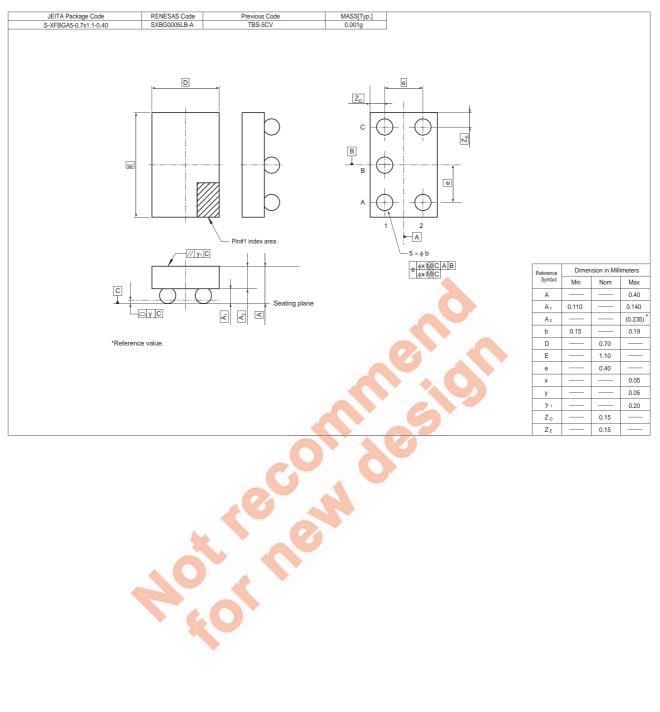








Package Dimensions





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Renesas Technology Korea Co., Ltd. Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea Tel: <82> (2) 796-3115, Fax: <82> (2) 796-2145

Renesas Technology Malaysia Sdn. Bhd Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jalan Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: <603> 7955-9390, Fax: <603> 7955-9510